

74VCX162244

Low Voltage 16-Bit Buffer/Line Driver with 3.6V Tolerant Inputs and Outputs and 26Ω Series Resistor in Outputs

General Description

The VCX162244 contains sixteen non-inverting buffers with 3-STATE outputs to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is nibble (4-bit) controlled. Each nibble has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

The 74VCX162244 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O capability up to 3.6V. The 74VCX162244 is also designed with 26Ω series resistors in the outputs. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus transceivers/transmitters.

The 74VCX162244 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- 26Ω series resistors in outputs
- t_{PD}
 - 3.3 ns max for 3.0V to 3.6V V_{CC}
 - 3.8 ns max for 2.3V to 2.7V V_{CC}
 - 7.6 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Supports live insertion and withdrawal
- Static Drive (I_{OH}/I_{OL})
 - ±12 mA @ 3.0V V_{CC}
 - ±8 mA @ 2.3V V_{CC}
 - ±3 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
 - Human body model > 2000V
 - Machine model > 200V

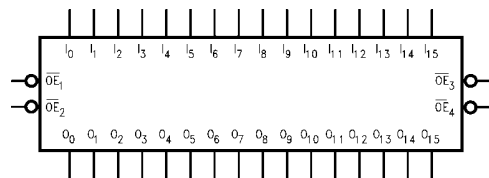
Note 1: To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74VCX162244MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

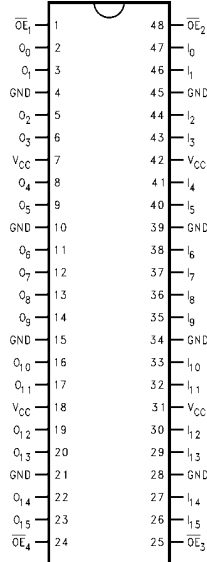
Logic Symbol



Pin Descriptions

Pin Names	Description
\overline{OE}_n	Output Enable Input (Active LOW)
I_0 – I_{15}	Inputs
O_0 – O_{15}	Outputs

Connection Diagram



Truth Tables

Inputs		Outputs
\overline{OE}_1	I_0-I_3	O_0-O_3
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
\overline{OE}_2	I_4-I_7	O_4-O_7
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
\overline{OE}_3	I_8-I_{11}	O_8-O_{11}
L	L	L
L	H	H
H	X	Z

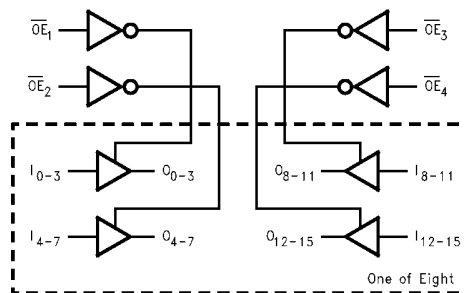
Inputs		Outputs
\overline{OE}_4	$I_{12}-I_{15}$	$O_{12}-O_{15}$
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
 L = LOW Voltage Level
 X = Immaterial (HIGH or LOW, inputs may not float)
 Z = High Impedance

Functional Description

The 74VCX162244 contains sixteen non-inverting buffers with 3-STATE outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of each other. The control pins may be shorted together to obtain full 16-bit operation. The 3-STATE outputs are controlled by an Output Enable (\overline{OE}_n) input. When \overline{OE}_n is LOW, the outputs are in the 2-state mode. When \overline{OE}_n is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the inputs.

Logic Diagram

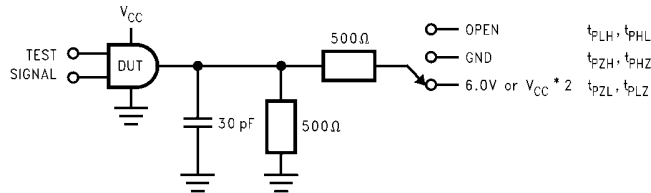


Absolute Maximum Ratings (Note 2)		Recommended Operating Conditions (Note 4)				
Supply Voltage (V_{CC})	-0.5V to +4.6V	Power Supply				
DC Input Voltage (V_I)	-0.5V to +4.6V	Operating	1.65V to 3.6V			
Output Voltage (V_O)		Data Retention Only	1.2V to 3.6V			
Outputs 3-STATE	-0.5V to +4.6V	Input Voltage	-0.3V to +3.6V			
Outputs Active (Note 3)	-0.5V to $V_{CC} + 0.5V$	Output Voltage (V_O)				
DC Input Diode Current (I_{IK}) $V_I < 0V$	-50 mA	Output in Active States	0V to V_{CC}			
DC Output Diode Current (I_{OK})		Output in 3-State	0.0V to 3.6V			
$V_O < 0V$	-50 mA	Output Current in I_{OH}/I_{OL}				
$V_O > V_{CC}$	+50 mA	$V_{CC} = 3.0V$ to 3.6V	± 12 mA			
DC Output Source/Sink Current (I_{OH}/I_{OL})	± 50 mA	$V_{CC} = 2.3V$ to 2.7V	± 8 mA			
DC V_{CC} or GND Current per Supply Pin (I_{CC} or GND)	± 100 mA	$V_{CC} = 1.65V$ to 2.3V	± 3 mA			
Storage Temperature Range (T_{STG})	-65°C to +150°C	Free Air Operating Temperature (T_A)	-40°C to +85°C			
		Minimum Input Edge Rate ($\Delta V/\Delta t$)				
		$V_{IN} = 0.8V$ to 2.0V, $V_{CC} = 3.0V$	10 ns/V			
		Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.				
		Note 3: I_O Absolute Maximum Rating must be observed.				
		Note 4: Floating or unused inputs must be held HIGH or LOW.				
DC Electrical Characteristics (2.7V < $V_{CC} \leq 3.6V$)						
Symbol	Parameter	Conditions	V_{CC} (V)	Min	Max	Units
V_{IH}	HIGH Level Input Voltage		2.7-3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7-3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100 \mu A$	2.7-3.6	$V_{CC} - 0.2$		V
		$I_{OH} = -6$ mA	2.7	2.2		V
		$I_{OH} = -8$ mA	3.0	2.4		V
		$I_{OH} = -12$ mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100 \mu A$	2.7-3.6		0.2	V
		$I_{OL} = 6$ mA	2.7		0.4	V
		$I_{OL} = 8$ mA	3.0		0.55	V
		$I_{OL} = 12$ mA	3.0		0.8	V
I_I	Input Leakage Current	$0 \leq V_I \leq 3.6V$	2.7-3.6		± 5.0	μA
I_{OZ}	3-STATE Output Leakage	$0 \leq V_O \leq 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.7-3.6		± 10	μA
I_{OFF}	Power-OFF Leakage Current	$0 \leq (V_I, V_O) \leq 3.6V$	0		10	μA
I_{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.7-3.6		20	μA
		$V_{CC} \leq (V_I, V_O) \leq 3.6V$ (Note 5)	2.7-3.6		± 20	μA
ΔI_{CC}	Increase in I_{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.7-3.6		750	μA
Note 5: Outputs disabled or 3-STATE only.						

DC Electrical Characteristics (2.3V ≤ V_{CC} ≤ 2.7V)						
Symbol	Parameter	Conditions	V _{CC} (V)	Min	Max	Units
V _{IH}	HIGH Level Input Voltage		2.3–2.7	1.6		V
V _{IL}	LOW Level Input Voltage		2.3–2.7		0.7	V
V _{OH}	HIGH Level Output Voltage	I _{OH} = –100 μA	2.3–2.7	V _{CC} – 0.2		V
		I _{OH} = –4 mA	2.3	2.0		V
		I _{OH} = –6 mA	2.3	1.8		V
		I _{OH} = –8 mA	2.3	1.7		V
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.3–2.7		0.2	V
		I _{OL} = 6 mA	2.3		0.4	V
		I _{OL} = 8 mA	2.3		0.6	V
I _I	Input Leakage Current	0 ≤ V _I ≤ 3.6V	2.3–2.7		±5.0	μA
I _{OZ}	3-STATE Output Leakage	0 ≤ V _O ≤ 3.6V V _I = V _{IH} or V _{IL}	2.3–2.7		±10	μA
I _{OFF}	Power-OFF Leakage Current	0 ≤ (V _I , V _O) ≤ 3.6V	0		10	μA
I _{CC}	Quiescent Supply Current	V _I = V _{CC} or GND	2.3–2.7		20	μA
		V _{CC} ≤ (V _I , V _O) ≤ 3.6V (Note 6)	2.3–2.7		±20	μA
Note 6: Outputs disabled or 3-STATE only.						
DC Electrical Characteristics (1.65V ≤ V_{CC} < 2.3V)						
Symbol	Parameter	Conditions	V _{CC} (V)	Min	Max	Units
V _{IH}	HIGH Level Input Voltage		1.65–2.3	0.65 × V _{CC}		V
V _{IL}	LOW Level Input Voltage		1.65–2.3		0.35 × V _{CC}	V
V _{OH}	HIGH Level Output Voltage	I _{OH} = –100 μA	1.65–2.3	V _{CC} – 0.2		V
		I _{OH} = –3 mA	1.65	1.25		V
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	1.65–2.3		0.2	V
		I _{OL} = 3mA	1.65		0.3	V
I _I	Input Leakage Current	0 ≤ V _I ≤ 3.6V	1.65–2.3		±5.0	μA
I _{OZ}	3-STATE Output Leakage	0 ≤ V _O ≤ 3.6V V _I = V _{IH} or V _{IL}	1.65–2.3		±10	μA
I _{OFF}	Power-OFF Leakage Current	0 ≤ (V _I , V _O) ≤ 3.6V	0		10	μA
I _{CC}	Quiescent Supply Current	V _I = V _{CC} or GND	1.65–2.3		20	μA
		V _{CC} ≤ (V _I , V _O) ≤ 3.6V (Note 7)	1.65–2.3		±20	μA
Note 7: Outputs disabled or 3-STATE only.						

AC Electrical Characteristics (Note 8)								
Symbol	Parameter	$T_A = -40^\circ\text{C to } +85^\circ\text{C}, C_L = 30\text{ pF}, R_L = 500\Omega$						Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 1.8V \pm 0.15V$		
		Min	Max	Min	Max	Min	Max	
t_{PHL}, t_{PLH}	Prop Delay	0.8	3.3	1.0	3.8	1.5	7.6	ns
t_{PZL}, t_{PZH}	Output Enable Time	0.8	3.8	1.0	5.1	1.5	9.8	ns
t_{PLZ}, t_{PHZ}	Output Disable Time	0.8	3.6	1.0	4.0	1.5	7.2	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 9)		0.5		0.5		0.75	ns
<p>Note 8: For $C_L = 50\text{ pF}$, add approximately 300 ps to the AC maximum specification.</p> <p>Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).</p>								
Dynamic Switching Characteristics								
Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = +25^\circ\text{C}$	Units			
				Typical				
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 30\text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8 2.5 3.3	0.15 0.25 0.35	V			
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 30\text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8 2.5 3.3	-0.15 -0.25 -0.35	V			
V_{OHV}	Quiet Output Dynamic Valley V_{OH}	$C_L = 30\text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8 2.5 3.3	1.55 2.05 2.65	V			
Capacitance								
Symbol	Parameter	Conditions	$T_A = +25^\circ\text{C}$	Units				
			Typical					
C_{IN}	Input Capacitance	$V_{CC} = 1.8, 2.5V\text{ or }3.3V, V_I = 0V\text{ or }V_{CC}$	6	pF				
C_{OUT}	Output Capacitance	$V_I = 0V\text{ or }V_{CC}, V_{CC} = 1.8V, 2.5V\text{ or }3.3V$	7	pF				
C_{PD}	Power Dissipation Capacitance	$V_I = 0V\text{ or }V_{CC}, f = 10\text{ MHz}, V_{CC} = 1.8V, 2.5V\text{ or }3.3V$	20	pF				

AC Loading and Waveforms



TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V at $V_{CC} = 3.3 \pm 0.3V$; $V_{CC} \times 2$ at $V_{CC} = 2.5 \pm 0.2V$; $1.8 \pm 0.15V$
t_{PZH}, t_{PHZ}	GND

FIGURE 1. AC Test Circuit

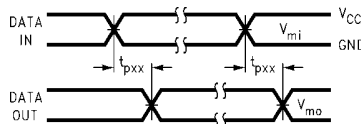


FIGURE 2. Waveform for Inverting and Non-Inverting Functions

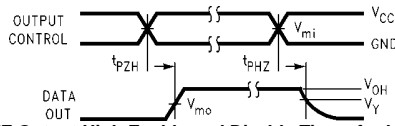


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

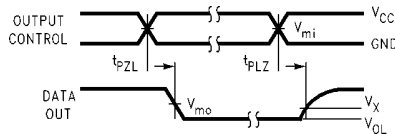


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

Symbol	V_{CC}		
	$3.3V \pm 0.3V$	$2.5V \pm 0.2V$	$1.8V \pm 0.15V$
V_{mi}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_{mo}	1.5V	$V_{CC}/2$	$V_{CC}/2$
V_X	$V_{OL} + 0.3V$	$V_{OL} + 0.15V$	$V_{OL} + 0.15V$
V_Y	$V_{OH} - 0.3V$	$V_{OH} - 0.15V$	$V_{OH} - 0.15V$

